

CITATION REPORT

List of articles citing

GaN-Based VCSELs

DOI: 10.1007/978-3-642-24986-0_13
Springer Series in Optical Sciences, 2013, , 403-427.

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#	Paper	IF	Citations
3	What is the problem with GaN-based VCSELs?. 2013 ,		2
2	GaN-based vertical-cavity laser performance improvements using tunnel-junction-cascaded active regions. <i>Applied Physics Letters</i> , 2014 , 105, 011116	3.4	11
1	Room-temperature 2D semiconductor activated vertical-cavity surface-emitting lasers. <i>Nature Communications</i> , 2017 , 8, 543	17.4	74